# NSN 5961-00-480-1791

Transistor - Page 1 of 1



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## Inclosure Material:

Metal

**Overall Length:** 

0.350 inches

### **Overall Diameter:**

0.820 inches

# Mounting Facility Quantity:

2

#### Internal Configuration:

Junction contact

#### Electrode Internally-electrically Connected To Case:

Collector

Internal Junction Configuration:

Npn

#### **Mounting Method:**

Unthreaded hole

# Features Provided:

Hermetically sealed case

#### Semiconductor Material:

Silicon

#### Voltage Rating In Volts Per Characteristic:

80.0 breakdown voltage, collector-to-base, emitter open and 60.0 breakdown voltage, collector-to-emitter, base open and 7.0 breakdown voltage, emitter-to-base, collector open

#### **Current Rating Per Characteristic:**

10.00 amperes source cutoff current and 4.00 amperes source cutoff current

#### **Power Rating Per Characteristic:**

150.0 watts small-signal input power, common-collector absolute

#### Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

#### Test Data Document:

94580-10031209 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing,

etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

#### **Terminal Type And Quantity:**

2 pin and 1 case Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0